

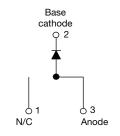
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## **High Performance Schottky Rectifier, 8 A**



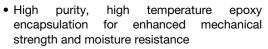
**D2PAK (TO-263AB)** 



PRODUCT SUMMARY								
I <sub>F(AV)</sub>	8 A							
$V_{R}$	80 V, 100 V							
V <sub>F</sub> at I <sub>F</sub>	0.72 V							
I <sub>RM</sub> max.	7 mA at 125 °C							
T <sub>J</sub> max.	175 °C							
E <sub>AS</sub>	7.5 mJ							
Package	D2PAK (TO-263AB)							
Diode variation	Single							

#### **FEATURES**

- 175 °C T<sub>J</sub> operation
- Low forward voltage drop
- High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

### **DESCRIPTION**

The VS-8TQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	VALUES	UNITS							
I <sub>F(AV)</sub>	Rectangular waveform	8	A						
V <sub>RRM</sub>	Range	80, 100	V						
I <sub>FSM</sub>	$t_p = 5 \mu s sine$	850	А						
V <sub>F</sub>	8 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.58	V						
T <sub>J</sub>	Range	-55 to +175	°C						

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-8TQ080SPbF	VS-8TQ100SPbF	UNITS					
Maximum DC reverse voltage	$V_{R}$	80	100	V					
Maximum working peak reverse voltage	$V_{RWM}$	00	100	V					

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS					
Maximum average forward current See fig. 5	I <sub>F(AV)</sub>	50 % duty cycle at T <sub>C</sub> = 157 °C	8	Α					
Maximum peak one cycle non-repetitive surge current	I <sub>FSM</sub>	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	850	А				
See fig. 7		10 ms sine or 6 ms rect. pulse	V <sub>RRM</sub> applied	230					
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 0.50 A, L = 60 mH		7.50	mJ				
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		0.50	Α				



# VS-8TQ080SPbF, VS-8TQ100SPbF

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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS				
		8 A	T _ 25 °C	0.72				
Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	16 A	T <sub>J</sub> = 25 °C	0.88	V			
See fig. 1	VFM (1)	8 A	T <sub>.1</sub> = 125 °C	0.58	V			
		16 A	1J=125 C	0.69				
Maximum reverse leakage current	1 (1)	T <sub>J</sub> = 25 °C	V <sub>B</sub> = Rated V <sub>B</sub>	0.55	mA			
See fig. 2	I <sub>RM</sub> (1)	T <sub>J</sub> = 125 °C	v <sub>R</sub> = nateu v <sub>R</sub>	7				
Maximum junction capacitance	C <sub>T</sub>	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		500	pF			
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 n	8	nH				
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>	10 000	V/µs				

#### Note

 $<sup>^{(1)}\,</sup>$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C			
Maximum thermal resistance, junction to case		R <sub>thJC</sub>	DC operation See fig. 4	2.0	°C/W			
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth, and greased	0.50				
Approximate weight				2	g			
Approximate weight				0.07	oz.			
Maunting toward	minimum			6 (5)	kgf · cm			
Mounting torque	maximum			12 (10)	(lbf · in)			
Marking device			Coop at de DODAK	8TQ(	080S			
			Case style D2PAK	8TQ <sup>-</sup>	100S			

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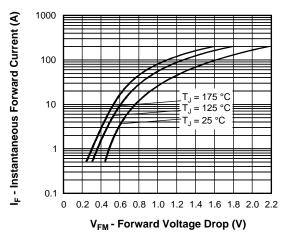


Fig. 1 - Maximum Forward Voltage Drop Characteristics

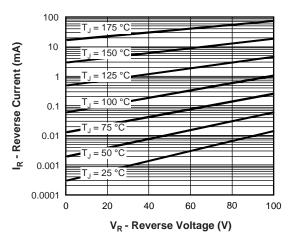


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

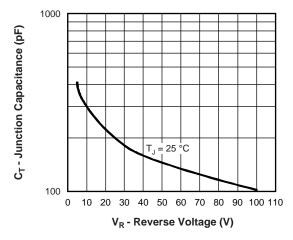


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

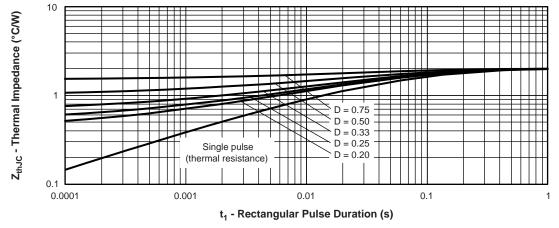


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

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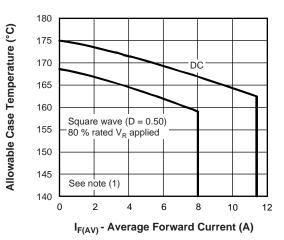


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

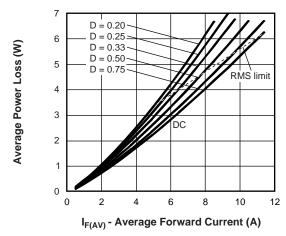


Fig. 6 - Forward Power Loss Characteristics

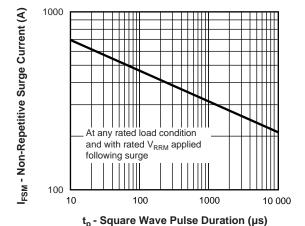


Fig. 7 - Maximum Non-Repetitive Surge Current

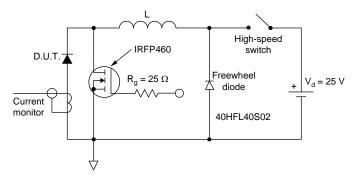


Fig. 8 - Unclamped Inductive Test Circuit

### Note

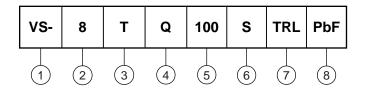
 $^{(1)}$  Formula used: T<sub>C</sub> = T<sub>J</sub> - (Pd + Pd<sub>REV</sub>) x R<sub>thJC</sub>; Pd = forward power loss = I<sub>F(AV)</sub> x V<sub>FM</sub> at (I<sub>F(AV)</sub>/D) (see fig. 6); Pd<sub>REV</sub> = inverse power loss = V<sub>R1</sub> x I<sub>R</sub> (1 - D); I<sub>R</sub> at V<sub>R1</sub> = 80 % rated V<sub>R</sub>

## VS-8TQ080SPbF, VS-8TQ100SPbF

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### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

2 - Current rating (8 A)

Gircuit configuration: T = TO-220

Schottky "Q" series

080 = 80 V 100 = 100 V

6 - S = D<sup>2</sup>PAK

7 - • None = tube (50 pieces)

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

PbF = lead (Pb)-free

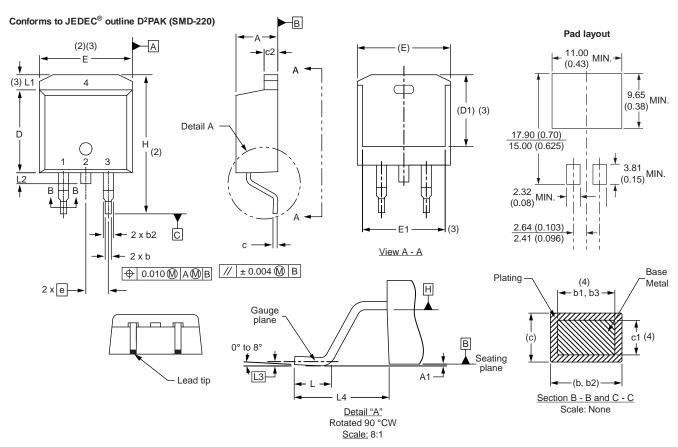
LINKS TO RELATED DOCUMENTS							
Dimensions www.vishay.com/doc?95046							
Part marking information	www.vishay.com/doc?95054						
Packaging information	www.vishay.com/doc?95032						
SPICE models	www.vishay.com/doc?96227						



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### D<sup>2</sup>PAK

### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INC	INCHES		NOTES	SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

#### Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



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